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### Vishay Semiconductors

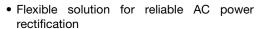
## Thyristor High Voltage, Phase Control SCR, 30 A



PRIMARY CHARACTERISTICS					
I <sub>T(AV)</sub> 20 A					
V <sub>DRM</sub> /V <sub>RRM</sub>	1200 V				
V <sub>TM</sub>	1.3 V				
I <sub>GT</sub>	45 mA				
T <sub>J</sub>	-40 °C to 125 °C				
Package	TO-247AD 3L				
Circuit configuration	Single SCR				

#### **FEATURES**

- AEC-Q101 qualified
- Meets JESD 201 class 1A whisker test





- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **APPLICATIONS**

- · On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

#### **DESCRIPTION**

The VS-30TPS12LHM3 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications.

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER TEST CONDITIONS VALUES UN						
I <sub>T(AV)</sub>	Sinusoidal waveform	20	۸			
I <sub>RMS</sub>		30	A			
V <sub>RRM</sub> /V <sub>DRM</sub>		1200	V			
I <sub>TSM</sub>		300	A			
$V_{T}$	20 A, T <sub>J</sub> = 25 °C	1.3	V			
dv/dt		500	V/µs			
di/dt		150	A/µs			
T <sub>J</sub>		-40 to +125	°C			

VOLTAGE RATINGS							
PART NUMBER	V <sub>RRM</sub> / V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> / I <sub>DRM</sub> AT 125 °C mA				
VS-30TPS12LHM3	1200	1300	10				



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS
Maximum average on-state current	I <sub>T(AV)</sub>	T <sub>C</sub> = 95 °C, 180° conduction	half sine wave	20	
Maximum RMS on-state current	I <sub>RMS</sub>			30	Α
Maximum peak, one-cycle	,	10 ms sine pulse, rated V <sub>RRN</sub>	<sub>d</sub> applied	250	A
non-repetitive surge current	I <sub>TSM</sub>	10 ms sine pulse, no voltage	reapplied	300	
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRN</sub>	<sub>d</sub> applied	310	A <sup>2</sup> s
Maximum I-t for fusing	1-1	10 ms sine pulse, no voltage reapplied		442	A-5
Maximum $I^2\sqrt{t}$ for fusing	I²√t	t = 0.1 ms to 10 ms, no voltage reapplied		4420	A²√s
Maximum on-state voltage drop	$V_{TM}$	20 A, T <sub>J</sub> = 25 °C		1.3	V
On-state slope resistance	r <sub>t</sub>	T 405 00		12	mΩ
Threshold voltage	V <sub>T(TO)</sub>	T <sub>J</sub> = 125 °C		1.0	V
Maximum reverse and direct leakage	1 /1	T <sub>J</sub> = 25 °C	\/ rated\/ /\/	0.5	
current	I <sub>RM</sub> /I <sub>DM</sub>	T <sub>J</sub> = 125 °C	$V_R = \text{rated } V_{RRM} / V_{DRM}$	10	A
Maximum holding current	I <sub>H</sub>	Anode supply = 6 V, resistive load, initial $I_T$ = 1 A, $T_J$ = 25 °C		150	mA
Maximum latching current	ΙL	Anode supply = 6 V, resistive load, T <sub>J</sub> = 25 °C		200	
Maximum rate of rise of off-state voltage	dV/dt	T <sub>J</sub> = T <sub>J</sub> maximum, linear to 80 % V <sub>DRM</sub> , R <sub>g</sub> -k = open		500	V/µs
Maximum rate of rise of turned-on current	dl/dt			150	A/µs

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum peak gate power	P <sub>GM</sub>		8.0	w	
Maximum average gate power	P <sub>G(AV)</sub>		2.0	VV	
Maximum peak positive gate current	+I <sub>GM</sub>		1.5	Α	
Maximum peak negative gate voltage	-V <sub>GM</sub>		10	V	
	I <sub>GT</sub>	Anode supply = 6 V, resistive load, $T_J = -10  ^{\circ}\text{C}$	60	mA	
Maximum required DC gate current to trigger		Anode supply = 6 V, resistive load, $T_J = 25$ °C	45		
		Anode supply = 6 V, resistive load, $T_J = 125$ °C	20		
		Anode supply = 6 V, resistive load, $T_J = -10  ^{\circ}\text{C}$	2.5		
Maximum required DC gate voltage to trigger	V <sub>GT</sub>	Anode supply = 6 V, resistive load, $T_J = 25$ °C	2.0	V	
300		Anode supply = 6 V, resistive load, $T_J = 125$ °C	1.0	V	
Maximum DC gate voltage not to trigger	$V_{GD}$	T = 125 °C V = rated value	0.25		
Maximum DC gate current not to trigger	I <sub>GD</sub>	T <sub>J</sub> = 125 °C, V <sub>DRM</sub> = rated value	2.0	mA	

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Typical turn-on time	t <sub>gt</sub>	T <sub>J</sub> = 25 °C	0.9			
Typical reverse recovery time	t <sub>rr</sub>	T <sub>.I</sub> = 125 °C	4	μs		
Typical turn-off time	tq	1J = 125 C	110			

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	SYMBOL TEST CONDITIONS		UNITS	
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-40 to 125	°C	
Maximum thermal resistation to case	resistance, R <sub>thJC</sub>		DC aparation	0.8		
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub> DC operation		40	°C/W	
Maximum thermal resistate case to heatsink	ince,	R <sub>thCS</sub>	Mounting surface, smooth and greased	0.2		
Approximate weight				6	g	
Approximate weight				0.21	oz.	
Mounting torque —	minimum			6 (5)	kgf · cm	
	maximum			12 (10)	(lbf · in)	
Marking device Case style TO-247AD 3L 30TPS		S12LH				

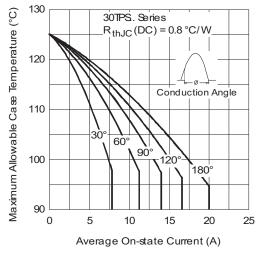


Fig. 1 - Current Rating Characteristics

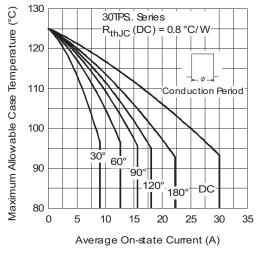


Fig. 2 - Current Rating Characteristics

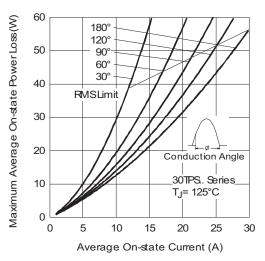


Fig. 3 - On-State Power Loss Characteristics

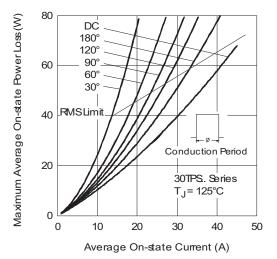


Fig. 4 - On-State Power Loss Characteristics

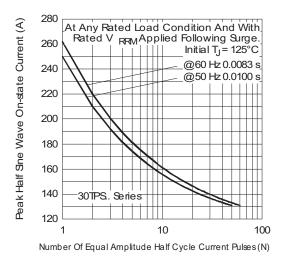


Fig. 5 - Maximum Non-Repetitive Surge Current

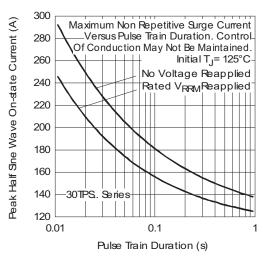


Fig. 6 - Maximum Non-Repetitive Surge Current

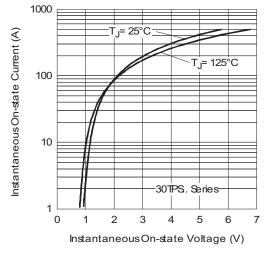


Fig. 7 - On-State Voltage Drop Characteristics

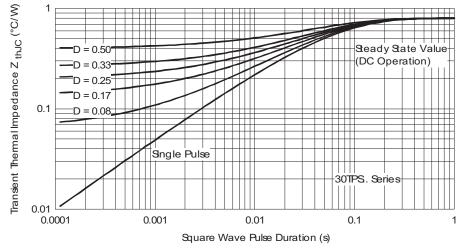


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

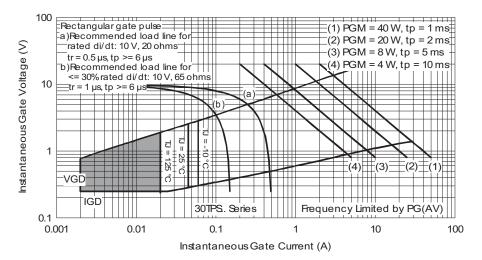
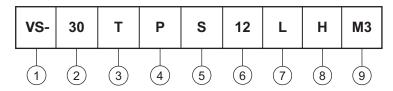


Fig. 9 - Gate Characteristics

#### **ORDERING INFORMATION TABLE**

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (30 = 30 A)
- 3 Circuit configuration:

T = Thyristor

- 4 P = TO-247 package
- 5 Type of silicon:

S = Standard recovery rectifier

- 6 Voltage code x 100 = V<sub>RRM</sub> --------- 12 = 1200 V
- 7 Package L = long lead
- 8 H = AEC-Q101 qualified
- 9 Environmental digit:

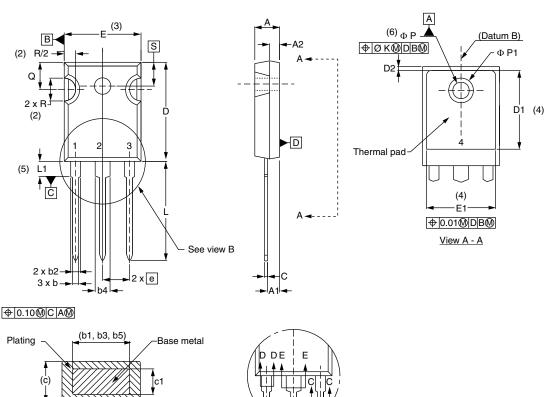
M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-30TPS12LHM3	25	500	Antistatic plastic tubes			

LINKS TO RELATED DOCUMENTS				
Dimensions TO-247AD 3L <u>www.vishay.com/doc?95626</u>				
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007		

### **TO-247AD 3L**

### **DIMENSIONS** in millimeters and inches



View B

SYMBOL	MILLIMETERS		INC	NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
О	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

Section C - C, D - D, E - E

SYMBOL	MILLIM	IETERS	INC	NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	BSC	
ØΚ	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	ı	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	BSC	
•	•			•	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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